电子电路与系统基础(1)---线性电路---2020秋季学期

第9讲: 串联RLC分压分析

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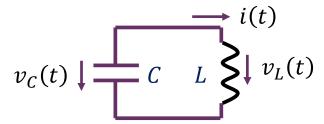
## 串联RLC分压分析-时域分析 内容

- 同属性元件分压分流电路
  - 纯阻串联分压、并联分流电路
  - 纯容串联分压、并联分流电路
  - 纯感串联分压、并联分流电路
- 阻容分压电路与分流电路
  - 直流激励、阶跃激励、正弦激励、冲激激励、方波激励
  - 阻感分压分流同理,均属一阶动态系统分析
- 阻容感分压电路和分流电路: 二阶动态系统分析
  - 串联RLC分压分析: 对偶的并联RLC分流分析对偶表述即可
    - 时域分析: 一般性分析
    - 时频分析: 二阶滤波器

#### 串联RLC分压分析----时域分析

- ■二阶LTI系统的系统参量
  - 自由振荡频率、阻尼系数
- ■状态方程和微分方程
  - 特征方程和特征根
- 解的形态
  - 待定系数法
  - ■五要素法
    - 欠阻尼: 减幅正弦振荡
      - 无阻尼: 等幅正弦振荡
      - 过阻尼: 指数衰减
- ■作业选讲
  - ■稳态响应

# LC谐振腔的自由振荡 正弦振荡



$$\frac{1}{C} \int \left(-i(t)\right) dt = \frac{1}{C} \int i_C(t) dt = v_C(t) = v_L(t) = L \frac{di_L(t)}{dt} = L \frac{di(t)}{dt}$$

**KCL** 

GOL

GOL

KCL

$$-\frac{i(t)}{C} = L\frac{d^2i(t)}{dt^2}$$

$$-\frac{i(t)}{C} = L\frac{d^2i(t)}{dt^2} \qquad \frac{d^2i(t)}{dt^2} + \frac{i(t)}{LC} = 0$$

电感电流

$$i(t) = I_0 \cos\left(\frac{1}{\sqrt{LC}}t + \varphi_0\right) = I_0 \cos(\omega_0 t + \varphi_0)$$

由电容初始电压, 电感初始电流确定, 同学自行练习确定: 假设 $i_L(0)$ ,  $v_c(0)$ 己知

电容电压 
$$v(t) = -\omega_0 L I_0 \sin(\omega_0 t + \varphi_0) = -Z_0 I_0 \sin(\omega_0 t + \varphi_0)$$

$$\omega_0 = \frac{1}{\sqrt{LC}}$$

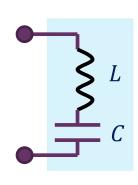
 $\omega_0 = \frac{1}{\sqrt{IC}}$  **LC**谐振腔的自由振荡频率 rad/s

$$Z_0 = \omega_0 L = \sqrt{\frac{L}{C}} = \frac{1}{\omega_0 C}$$
 **LC**谐振腔的特征阻抗  $\Omega$ 

$$E_C(t) + E_L(t) = \frac{1}{2}Cv^2(t) + \frac{1}{2}Li^2(t) = \frac{1}{2}Cv^2(0) + \frac{1}{2}Li^2(0)$$

纯LC谐振腔内无能量 损耗, 电容电能和电感 磁能之间的相互转换以 正弦振荡的形态维持

## 对LC串联谐振腔和并联谐振腔的描述

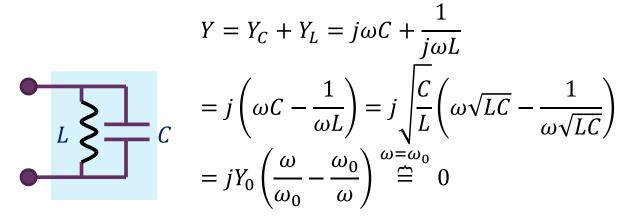


$$Z = Z_L + Z_C = j\omega L + \frac{1}{j\omega C}$$

$$= j\left(\omega L - \frac{1}{\omega C}\right) = j\sqrt{\frac{L}{C}}\left(\omega\sqrt{LC} - \frac{1}{\omega\sqrt{LC}}\right)$$

$$= jZ_0\left(\frac{\omega}{\omega_0} - \frac{\omega_0}{\omega}\right) \stackrel{\omega = \omega_0}{=} 0$$

#### 谐振频点上,串联LC短路



#### 谐振频点上,并联LC开路

 $\omega_0 = \frac{1}{\sqrt{LC}}$  rad/s

自由振荡频率谐振频率

$$Z_0 = \sqrt{\frac{L}{C}} = \omega_0 L = \frac{1}{\omega_0 C}$$

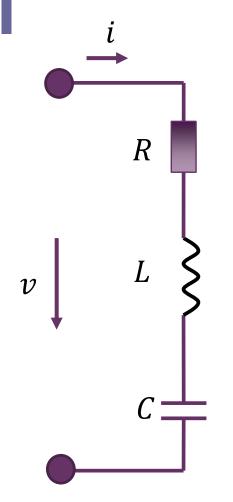
特征阻抗:恰好是自由振荡频点的电感或电容电抗值

$$\omega_0 = \frac{1}{\sqrt{LC}}$$
  $rad/s$ 

$$Y_0 = \sqrt{\frac{C}{L}} = \omega_0 C = \frac{1}{\omega_0 L}$$

LC谐振腔特征导纳

#### 串联RLC系统参量



$$\xi = \frac{1}{2Q} = \frac{R}{2Z_0}$$

$$Z(j\omega) = Z_R + Z_L + Z_C = R + j\omega L + \frac{1}{j\omega C} = R + jZ_0 \left(\frac{\omega}{\omega_0} - \frac{\omega_0}{\omega}\right)$$
$$= R\left(1 + j\frac{Z_0}{R}\left(\frac{\omega}{\omega_0} - \frac{\omega_0}{\omega}\right)\right) = R\left(1 + jQ\left(\frac{\omega}{\omega_0} - \frac{\omega_0}{\omega}\right)\right)$$

自由振荡频率 
$$\omega_0 = \frac{1}{\sqrt{LC}}$$
 rad/s

特征阻抗 
$$Z_0 = \sqrt{\frac{L}{C}} = \omega_0 L = \frac{1}{\omega_0 C} \quad \Omega$$

品质因数 
$$Q = \frac{Z_0}{R} = \frac{虚功}{实功}$$

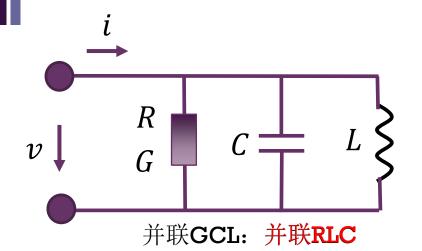
$$s = j\omega$$

$$Z(s) = R + sL + \frac{1}{sC} = \frac{s^2LC + sRC + 1}{sC} = \frac{s^2 + s\frac{R}{L} + \frac{1}{LC}}{\frac{s}{L}}$$

$$\xi = \frac{1}{2Q} = \frac{R}{2Z_0}$$

$$= R \frac{s^2 + \frac{\omega_0}{Q}s + \omega_0^2}{\frac{\omega_0}{Q}s} = R \frac{s^2 + 2\xi\omega_0 s + \omega_0^2}{2\xi\omega_0 s}$$

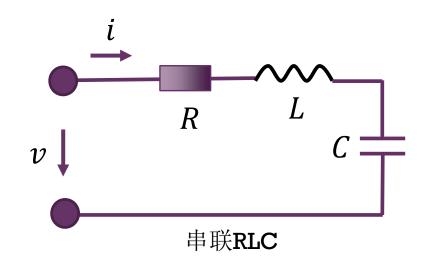
### 并联RLC对偶串联RLC



$$\omega_0 = \frac{1}{\sqrt{CL}} = \frac{1}{\sqrt{LC}} \quad \frac{rad/s}{}$$

$$Y_0 = \sqrt{\frac{C}{L}} = \omega_0 C = \frac{1}{\omega_0 L}$$

$$\xi = \frac{1}{2Q} = \frac{G}{2Y_0}$$



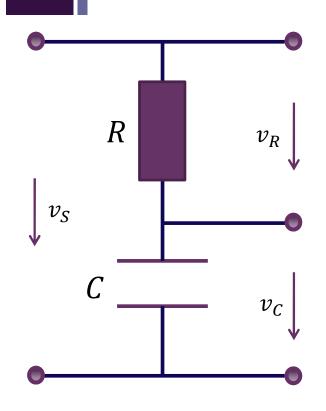
$$\omega_0 = \frac{1}{\sqrt{LC}}$$
 rad/s

$$Z_0 = \sqrt{\frac{L}{C}} = \omega_0 L = \frac{1}{\omega_0 C}$$

$$Q = \frac{Z_0}{R} = \frac{$$
 虚功 = 电抗 =  $\frac{\omega_0 L}{R}$ 

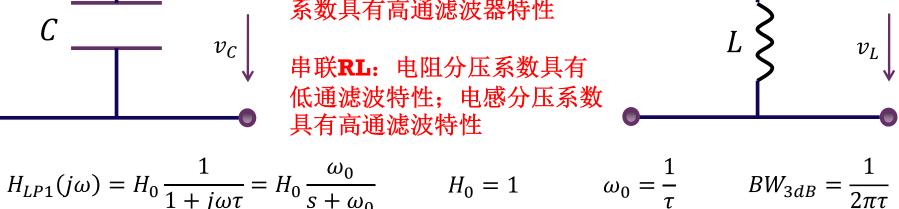
$$\xi = \frac{1}{2Q} = \frac{R}{2Z_0} \quad {}_{11/6/2020}$$

## 回顾:一阶RC分压、RL分压分析



串联RC: 电容低频开路,分 压系数为1, 电容高频短路, 分压系数为0: 说明电容分压 为输入信号中的低频分量,电 容分压系数具有低通滤波特性; 电阳分压系数在高频为1、低 频为0,说明电阻分压为输入 信号中的高频分量,电阻分压 系数具有高通滤波器特性

串联RL: 电阻分压系数具有 低通滤波特性; 电感分压系数 具有高通滤波特性

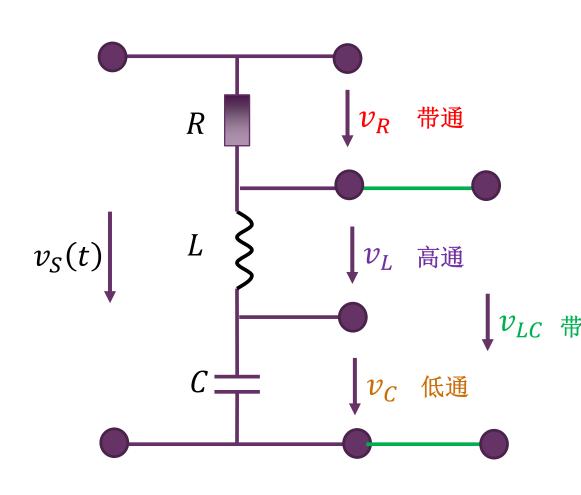


$$H_{HP1}(j\omega) = H_0 \frac{j\omega\tau}{1 + j\omega\tau} = H_0 \frac{s}{s + \omega_0} \qquad \tau = RC, GL \qquad s = j\omega \qquad f_{3dB} = \frac{1}{2\pi}$$

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11/6/2020

#### 串联RLC分压分析: 典型的二阶滤波特性



电感高频开路,分担的是输入电压中的高频分量,以电感分压为输出则具 高通滤波特性

电容低频开路,分担的是输入电压中 的低频分量,以电容分压为输出则具 低通滤波特性

谐振频点串联**LC**短路,电阻分担的 是输入电源中的中间频率分量,以电 阻分压为输出则具带通滤波特性

以串联LC分压为输出者,则具带阻滤波特性:谐振频点LC短路无输出,而低频电容开路、高频电感开路使得串联LC均获得全部分压

## 二阶滤波器传递函数典型形态

$$H_{LP2} = H_{vc} = \frac{\frac{1}{j\omega C}}{R + j\omega L + \frac{1}{j\omega C}} = \frac{1}{s^2 LC + sRC + 1} = \frac{\frac{1}{LC}}{s^2 + s\frac{R}{L} + \frac{1}{LC}} = \frac{\omega_0^2}{s^2 + 2\xi\omega_0 s + \omega_0^2}$$

$$H_{LP2} = H_{v_C} = \frac{\frac{1}{j\omega C}}{R + j\omega L + \frac{1}{j\omega C}} = \cdots H_0 \frac{\omega_0^2}{s^2 + 2\xi\omega_0 s + \omega_0^2}$$
 
$$\qquad \qquad \omega_0 = \frac{1}{\sqrt{LC}}$$
 二阶系统自由振荡

$$H_{HP2} = H_{v_L} = \frac{j\omega L}{R + j\omega L + \frac{1}{i\omega C}} = \cdots H_0 \frac{s^2}{s^2 + 2\xi\omega_0 s + \omega_0^2} \qquad \xi = \frac{R}{2Z_0} = \frac{1}{2}R\sqrt{\frac{C}{L}}$$

$$H_{BP2} = H_{v_R} = \frac{R}{R + j\omega L + \frac{1}{j\omega C}} = \cdots H_0 \frac{2\xi \omega_0 s}{s^2 + 2\xi \omega_0 s + \omega_0^2}$$

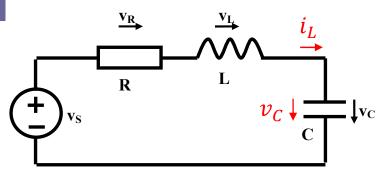
$$H_{BS2} = H_{v_{LC}} = \frac{j\omega L + \frac{1}{j\omega C}}{R + j\omega L + \frac{1}{j\omega C}} = \cdots H_0 \frac{s^2 + \omega_0^2}{s^2 + 2\xi\omega_0 s + \omega_0^2}$$
 滤波器中心频点传递系数

$$\omega_0 = \frac{1}{\sqrt{LC}}$$

$$\xi = \frac{R}{2Z_0} = \frac{1}{2}R\sqrt{\frac{C}{L}}$$

$$s = j\omega$$

## RLC串联电路一般性分析: 状态方程法



状态方程: 就是以电路中的n个独立 状态变量为未知量列写的n个一阶微 分方程组,方程左侧为状态变量的一 阶微分形式,方程右侧为状态变量和 激励变量的代数方程形式

$$\begin{aligned} v_S &= v_R + v_L + v_C = i_L R + L \frac{d}{dt} i_L + v_C & i_L = i_C = C \frac{d}{dt} v_C \\ \frac{d}{dt} v_C &= \frac{1}{C} i_L & \frac{d}{dt} \begin{bmatrix} v_C \\ i_L \end{bmatrix} = \begin{bmatrix} 0 & \frac{1}{C} \\ -\frac{1}{L} & -\frac{R}{L} \end{bmatrix} \begin{bmatrix} v_C \\ i_L \end{bmatrix} + \begin{bmatrix} 0 \\ \frac{1}{L} v_S \end{bmatrix} \end{aligned}$$

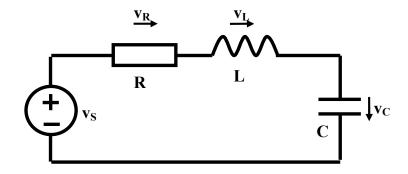
$$\frac{d}{dt} i_L = -\frac{R}{L} i_L - \frac{1}{L} v_C + \frac{1}{L} v_S$$

$$\begin{bmatrix} v_{R,out} \\ v_{L,out} \\ v_{C,out} \end{bmatrix} = \begin{bmatrix} 0 & R \\ -1 & -R \\ 1 & 0 \end{bmatrix} \begin{bmatrix} v_C \\ i_L \end{bmatrix} + \begin{bmatrix} 0 \\ 1 \\ 0 \end{bmatrix} v_S$$

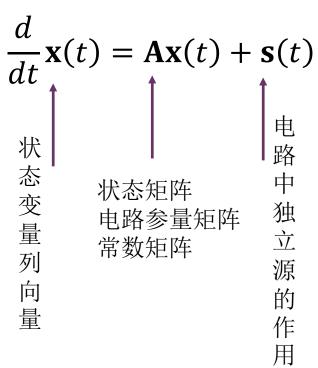
状态方程法的好处是,一次性求出状态变量后,它们作为系统内蕴的源(或者由替代定理,用恒压源 $v_c(t)$ 替代电容 $\mathbf{C}$ ,用恒流源 $i_L(t)$ 替代电感 $\mathbf{L}$ ),与外加激励源共同决定系统内的任何电量:由叠加定理可知,系统中的任何电量均可表述为状态变量和外加激励源的叠加形式

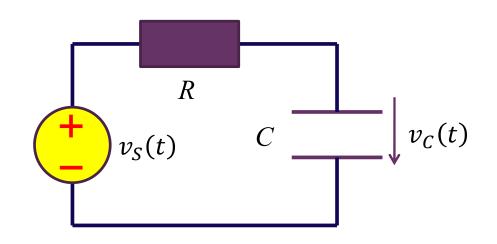
## LTI系统状态方程的一般形式

$$\frac{d}{dt} \begin{bmatrix} v_C \\ i_L \end{bmatrix} = \begin{bmatrix} 0 & \frac{1}{C} \\ -\frac{1}{L} & -\frac{R}{L} \end{bmatrix} \begin{bmatrix} v_C \\ i_L \end{bmatrix} + \begin{bmatrix} 0 \\ \frac{1}{L} v_S \end{bmatrix}$$



#### LTI系统状态方程的一般形式





其形式同样适用一阶系统

$$\frac{d}{dt}v_C(t) = -\frac{1}{RC}v_C(t) + \frac{1}{RC}v_S(t)$$

## LTI状态方程求解的一般过程

#### 一阶LTI系统状态方程求解过程

$$\frac{d}{dt}x = ax + s$$

$$\frac{d}{dt}\left(e^{-at}x\right) = e^{-at}s$$

$$e^{-at}x(t)\Big|_{t_0}^t = \int_{t_0}^t e^{-a\lambda}s(\lambda)d\lambda$$

$$x(t) = e^{a(t-t_0)}x(t_0) + \int_{t_0}^t e^{a(t-\lambda)}s(\lambda)d\lambda$$

零输入响应 零状态响应

$$x(t) = x_{\infty}(t) + (x(t_0) - x_{\infty}(t_0))e^{a(t-t_0)}$$
 稳态响应 瞬态响应

#### 直接推广到高阶LTI系统

$$\frac{d}{dt}\mathbf{x} = \mathbf{A}\mathbf{x} + \mathbf{s}$$

$$\frac{d}{dt} \left( e^{-\mathbf{A}t} \mathbf{x} \right) = e^{-\mathbf{A}t} \mathbf{s}$$

$$e^{-\mathbf{A}t}\mathbf{x}(t)\Big|_{t_0}^t = \int_{t_0}^t e^{-\mathbf{A}\lambda}\mathbf{s}(\lambda)d\lambda$$

$$\mathbf{x}(t) = e^{\mathbf{A}(t-t_0)} \mathbf{x}(t_0) + \int_{t_0}^t e^{\mathbf{A}(t-\lambda)} \mathbf{s}(\lambda) d\lambda$$

零输入响应 零状态响应

$$\mathbf{x}(t) = \mathbf{x}_{\infty}(t) + e^{\mathbf{A}(t-t_0)}(\mathbf{x}(t_0) - \mathbf{x}_{\infty}(t_0))$$
 稳态响应 瞬态响应

 $(t \ge t_0)$ 

## LTI系统解的形态是确定的

$$\mathbf{x}(t) = \mathbf{x}_{\infty}(t) + e^{\mathbf{A}(t-t_0)} (\mathbf{x}(t_0) - \mathbf{x}_{\infty}(t_0))$$

由激励决定的稳态响应, 具有和激励相同的形态

通过状态转移矩阵的作用,当前 状态是由之前状态转移过来的

状态转移矩阵 
$$e^{At} = I + At + \frac{1}{2!}A^2t^2 + \frac{1}{3!}A^3t^3 + \cdots$$

$$= I + P\begin{bmatrix} \lambda_1 & & \\ & \cdot & \\ & & \lambda_n \end{bmatrix} P^{-1}t + \frac{1}{2!}P\begin{bmatrix} \lambda_1^2 & & \\ & \cdot & \\ & & \lambda_n^2 \end{bmatrix} P^{-1}t^2 + \cdots$$
 式,其叠加加权系数待定(和初值、激励源

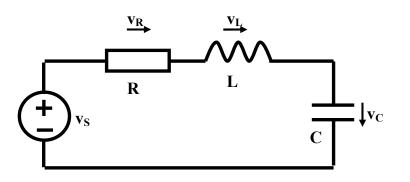
$$= P \begin{bmatrix} 1 + \lambda_1 t + \frac{1}{2!} \lambda_1^2 t^2 + \cdots \\ & \ddots \\ & & 1 + \lambda_n t + \frac{1}{2!} \lambda_n^2 t^2 + \cdots \end{bmatrix} P^{-1}$$
 有关);其中  $\lambda_k$ 是状态矩阵 A的特征根, 也是**LTI**系统 特征根

状态变量的瞬 态响应一定是  $e^{\lambda_k t}$ 的叠加形 /稳态响应均 特征根

征根求取

#### 二阶系统的特征参量是什么?

#### 人微分方程的形态入手进行研究



$$v_S = v_R + v_L + v_C = i_C R + L \frac{d}{dt} i_C + v_C$$

$$= RC \frac{d}{dt} v_C + LC \frac{d^2}{dt^2} v_C + v_C$$

$$\frac{d^2}{dt^2} v_C + \frac{R}{L} \frac{d}{dt} v_C + \frac{1}{LC} v_C = \frac{1}{LC} v_S$$

$$v_S = v_R + v_L + v_C = v_R + L\frac{d}{dt}i_R + \frac{1}{C}\int i_R dt$$

$$= v_R + \frac{L}{R}\frac{d}{dt}v_R + \frac{1}{RC}\int v_R dt$$

$$\frac{d}{dt}v_S = \frac{d}{dt}v_R + \frac{L}{R}\frac{d^2}{dt^2}v_R + \frac{1}{RC}v_R$$

$$\frac{d^2}{dt^2}v_R + \frac{R}{L}\frac{d}{dt}v_R + \frac{1}{LC}v_R = \frac{R}{L}\frac{d}{dt}v_S$$

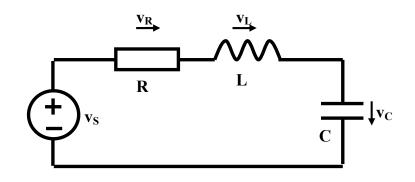
$$v_{S} = v_{R} + v_{L} + v_{C} = i_{L}R + v_{L} + \frac{1}{C}\int i_{L}dt$$

$$= \frac{R}{L}\int v_{L}dt + v_{L} + \frac{1}{LC}\int \int v_{L}dt^{2}$$

$$\frac{d^{2}}{dt^{2}}v_{S} = \frac{R}{L}\frac{d}{dt}v_{L} + \frac{d^{2}}{dt^{2}}v_{L} + \frac{1}{LC}v_{L}$$

$$\frac{d^{2}}{dt^{2}}v_{L} + \frac{R}{L}\frac{d}{dt}v_{L} + \frac{1}{LC}v_{L} = \frac{d^{2}}{dt^{2}}v_{S}$$

## 二阶LTI系统微分方程的一般形式



用电路中的任意电量,均可得 到形态完全一致的二阶微分电 路方程,仅仅是激励的形态不 同而已

$$\frac{d^2}{dt^2}v_C + \frac{R}{L}\frac{d}{dt}v_C + \frac{1}{LC}v_C = \frac{1}{LC}v_S$$

$$\frac{d^2}{dt^2}v_R + \frac{R}{L}\frac{d}{dt}v_R + \frac{1}{LC}v_R = \frac{R}{L}\frac{d}{dt}v_S$$

$$\frac{d^2}{dt^2}v_L + \frac{R}{L}\frac{d}{dt}v_L + \frac{1}{LC}v_L = \frac{d^2}{dt^2}v_S$$

$$\frac{d^2}{dt^2}x + 2\xi\omega_0 \frac{d}{dt}x + \omega_0^2 x = s_x$$

获得这个微分方程形式 是一定的,从频域看

$$(j\omega)^2 \dot{X} + 2\xi\omega_0(j\omega)\dot{X} + \omega_0^2 \dot{X} = \dot{S}_X$$

$$\frac{\dot{X}}{\dot{S}} = \frac{\dot{S}_X / \dot{S}}{s^2 + 2\xi\omega_0 s + \omega_0^2}$$

## 从微分方程求特征根的一般过程

假设n阶LTI动态系统的n阶微分方程为

$$\sum_{k=0}^{n} a_k \frac{d^k}{dt^k} x(t) = f(s_1(t), s_2(t), \dots)$$

$$a_n = 1$$

其中, x(t)是电路中的某个电量,可以是状态变量,也可以不是状态变量,对于 LTI系数,微分方程系数是由系统结构决定的常系数,前述分析表明,其齐次方程 (零输入情况)的解一定是指数 $X_0e^{\lambda t}$ 形式,其中, $\lambda$ 为其特征根。代入齐次方程

$$\sum_{k=0}^{n} a_k \frac{d^k}{dt^k} x(t) = \sum_{k=0}^{n} a_k \frac{d^k}{dt^k} (X_0 e^{\lambda t}) = \sum_{k=0}^{n} a_k X_0 \lambda^k e^{\lambda t} = X_0 e^{\lambda t} \sum_{k=0}^{n} a_k \lambda^k = 0$$

获得的n次多项式方程,就是LTI系统的特征方程,其根就是特征根

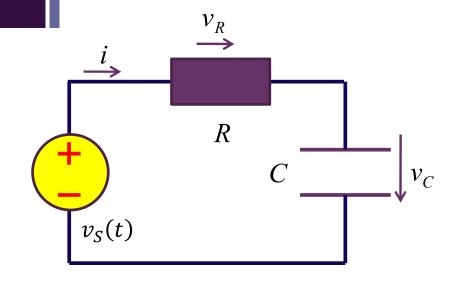
$$\sum_{k=0}^{n} a_k \lambda^k = 0$$

某种数学方法求解特征方程获得特征根后, 电量x(t)的解可以表述为

$$x(t) = x_{\infty}(t) + Ae^{\lambda_1 t} + Be^{\lambda_2 t} + \cdots$$

其中 $x_{\infty}(t)$ 是激励源决定的稳态响应,**n**个待定系数**A**、**B**、…由**n**个初值 $x(0^{+})$ 、  $\frac{d}{dt}x(0^+)$ 、...确定

#### 一阶系统特征根



一阶系统微分方程的一般形式

$$\frac{d}{dt}x(t) + \frac{1}{\tau}x(t) = s(t)$$

其特征根方程为

$$\lambda + \frac{1}{\tau} = 0$$

其特征根为  $\lambda = -\frac{1}{\tau}$ 

$$v_S(t) = v_R(t) + v_C(t)$$

$$=RC\frac{d}{dt}v_{C}(t)+v_{C}(t)$$

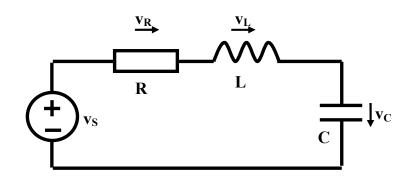
电路方程为

$$RC\frac{d}{dt}v_C(t) + v_C(t) = v_S(t)$$

$$\frac{d}{dt}v_{\mathcal{C}}(t) + \frac{1}{RC}v_{\mathcal{C}}(t) = \frac{1}{RC}v_{\mathcal{S}}(t)$$

特征根位于左半平面 特征根量纲: 1/s

## 二阶系统特征根: 自微分方程求取



$$\omega_0 = \frac{1}{\sqrt{LC}}$$

$$\xi = \frac{1}{2}R\sqrt{\frac{C}{L}} = \frac{R}{2Z_0}$$

$$Z_0 = \sqrt{\frac{L}{C}}$$

$$v_S = v_R + v_L + v_C = i_C R + L \frac{d}{dt} i_C + v_C$$
$$= RC \frac{d}{dt} v_C + LC \frac{d^2}{dt^2} v_C + v_C$$

$$\frac{d^2}{dt^2}v_C + \frac{R}{L}\frac{d}{dt}v_C + \frac{1}{LC}v_C = \frac{1}{LC}v_S$$

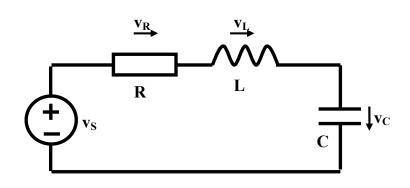
$$\frac{d^{2}}{dt^{2}}v_{C} + 2\xi\omega_{0}\frac{d}{dt}v_{C} + \omega_{0}^{2}v_{C} = \omega_{0}^{2}v_{S}$$

$$\lambda^2 + 2\xi\omega_0\lambda + \omega_0^2 = 0$$

$$\lambda_{1,2} = \left(-\xi \pm \sqrt{\xi^2 - 1}\right)\omega_0$$

特征根位于左半平面 特征根量纲: 1/s

## 二阶系统特征根: 自状态矩阵求取



$$\mathbf{A} = \begin{bmatrix} 0 & \frac{1}{C} \\ -\frac{1}{L} & -\frac{R}{L} \end{bmatrix} = \begin{bmatrix} 0 & \omega_0 Z_0 \\ -\omega_0 Y_0 & -2\xi\omega_0 \end{bmatrix} \qquad \begin{array}{c} 0 < \xi < 1 & \text{欠阻尼: 两个共轭复根} \\ \xi = 0 & \text{无阻尼: 两个共轭纯虚根} \end{array}$$

$$\det(\mathbf{A} - \lambda \mathbf{I}) = 0$$

$$\det\begin{bmatrix} -\lambda & \omega_0 Z_0 \\ -\omega_0 Y_0 & -2\xi \omega_0 - \lambda \end{bmatrix} = 0$$

特征方程  $\lambda^2 + 2\xi\omega_0\lambda + \omega_0^2 = 0$ 

临界阻尼:两个负实重根

阻尼系数:对电路中能量损耗的描述

## 待定系数法: 过阻尼 $\lambda_{1,2} = \left(-\xi \pm \sqrt{\xi^2 - 1}\right)\omega_0$

$$\lambda_{1,2} = \left(-\xi \pm \sqrt{\xi^2 - 1}\right)\omega_0$$

$$x(t) = x_{\infty}(t) + Ae^{\lambda_1 t} + Be^{\lambda_2 t} = x_{\infty}(t) + Ae^{-\frac{t}{\tau_1}} + Be^{-\frac{t}{\tau_2}}$$

$$\frac{d}{dt}x(t) = \frac{d}{dt}x_{\infty}(t) + A\lambda_1 e^{\lambda_1 t} + B\lambda_2 e^{\lambda_2 t}$$

指数衰减 长寿命项 短寿命项

$$x(0^+) = x_{\infty}(0^+) + A + B$$

$$\dot{x}(0^+) = \dot{x}_{\infty}(0^+) + A\lambda_1 + B\lambda_2$$

短期行为看短寿 命项(高频): 长期行为看长寿 命项(低频)

$$A = \frac{\lambda_2}{\lambda_2 - \lambda_1} (X_0 - X_{\infty 0}) - \frac{1}{\lambda_2 - \lambda_1} (\dot{X}_0 - \dot{X}_{\infty 0})$$

$$B = \frac{\lambda_1}{\lambda_1 - \lambda_2} (X_0 - X_{\infty 0}) - \frac{1}{\lambda_1 - \lambda_2} (\dot{X}_0 - \dot{X}_{\infty 0})$$

## 待定系数法: 欠阻尼

$$0 < \xi < 1$$

$$\lambda_{1,2} = \left(-\xi \pm \sqrt{\xi^2 - 1}\right)\omega_0 = \left(-\xi \pm j\sqrt{1 - \xi^2}\right)\omega_0$$
左半平面共轭复根

$$x(t) = x_{\infty}(t) + Ae^{\lambda_1 t} + Be^{\lambda_2 t}$$

$$= x_{\infty}(t) + Ae^{-\xi\omega_0 t + j\sqrt{1-\xi^2}\omega_0 t} + Be^{-\xi\omega_0 t - j\sqrt{1-\xi^2}\omega_0 t}$$

$$= x_{\infty}(t) + e^{-\xi \omega_0 t} \left( A e^{+j\sqrt{1-\xi^2}\omega_0 t} + B e^{-j\sqrt{1-\xi^2}\omega_0 t} \right)$$

$$=x_{\infty}(t)+e^{-\xi\omega_{0}t}\begin{pmatrix}A\cos\sqrt{1-\xi^{2}}\omega_{0}t+jA\sin\sqrt{1-\xi^{2}}\omega_{0}t\\+B\cos\sqrt{1-\xi^{2}}\omega_{0}t-jB\sin\sqrt{1-\xi^{2}}\omega_{0}t\end{pmatrix}$$

$$=x_{\infty}(t)+e^{-\xi\omega_{0}t}\begin{pmatrix}(A+B)\cos\sqrt{1-\xi^{2}}\omega_{0}t\\+j(A-B)\sin\sqrt{1-\xi^{2}}\omega_{0}t\end{pmatrix}$$

## 重定义待定系数: 欠阻尼

$$0 < \xi < 1$$

$$\lambda_{1,2} = \left(-\xi \pm \sqrt{\xi^2 - 1}\right)\omega_0 = \left(-\xi \pm j\sqrt{1 - \xi^2}\right)\omega_0$$

$$x(t) = x_{\infty}(t) + e^{-\xi\omega_0 t} \left( A\cos\sqrt{1 - \xi^2}\omega_0 t + B\sin\sqrt{1 - \xi^2}\omega_0 t \right)$$

$$\frac{d}{dt}x(t) = \frac{d}{dt}x_{\infty}(t) - \xi\omega_0 e^{-\xi\omega_0 t} \left(A\cos\sqrt{1-\xi^2}\omega_0 t + B\sin\sqrt{1-\xi^2}\omega_0 t\right) + \sqrt{1-\xi^2}\omega_0 e^{-\xi\omega_0 t} \left(-A\sin\sqrt{1-\xi^2}\omega_0 t + B\cos\sqrt{1-\xi^2}\omega_0 t\right)$$

$$x(0^{+}) = x_{\infty}(0^{+}) + A \qquad \frac{d}{dt}x(0^{+}) = \frac{d}{dt}x_{\infty}(0^{+}) - \xi\omega_{0}A + \sqrt{1 - \xi^{2}}\omega_{0}B$$

$$A = X_0 - X_{\infty 0}$$
 
$$B = \left(X_0 - X_{\infty 0} + \frac{X_0 - X_{\infty 0}}{\xi \omega_0}\right) \frac{\xi}{\sqrt{1 - \xi^2}}$$

## 五要素法

題尼系数 自由振荡频率 
$$x(t) = x_{\infty}(t) + (X_0 - X_{\infty 0})e^{-\xi\omega_0 t}\cos\sqrt{1 - \xi^2}\omega_0 t + \left(X_0 - X_{\infty 0} + \frac{\dot{X}_0 - \dot{X}_{\infty 0}}{\xi\omega_0}\right) \frac{\xi}{\sqrt{1 - \xi^2}}e^{-\xi\omega_0 t}\sin\sqrt{1 - \xi^2}\omega_0 t$$
 微分初值 
$$0 < \xi < 1$$

$$x(t) = x_{\infty}(t) + (X_0 - X_{\infty 0})e^{-\omega_0 t} + \left(X_0 - X_{\infty 0} + \frac{\dot{X}_0 - \dot{X}_{\infty 0}}{\omega_0}\right)\omega_0 t e^{-\omega_0 t}$$

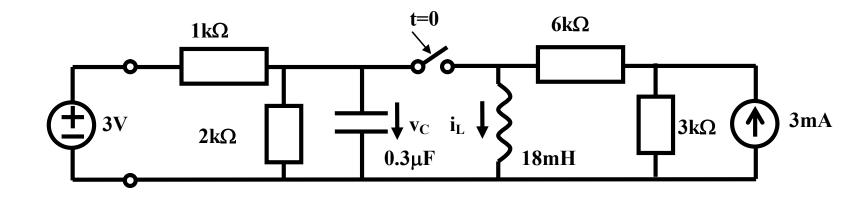
$$\xi = 1$$

$$x(t) = x_{\infty}(t) + (X_{0} - X_{\infty 0})e^{-\xi\omega_{0}t}\cosh\sqrt{\xi^{2} - 1}\omega_{0}t + \left(X_{0} - X_{\infty 0} + \frac{\dot{X}_{0} - \dot{X}_{\infty 0}}{\xi\omega_{0}}\right)\frac{\xi}{\sqrt{\xi^{2} - 1}}e^{-\xi\omega_{0}t}\sinh\sqrt{\xi^{2} - 1}\omega_{0}t$$

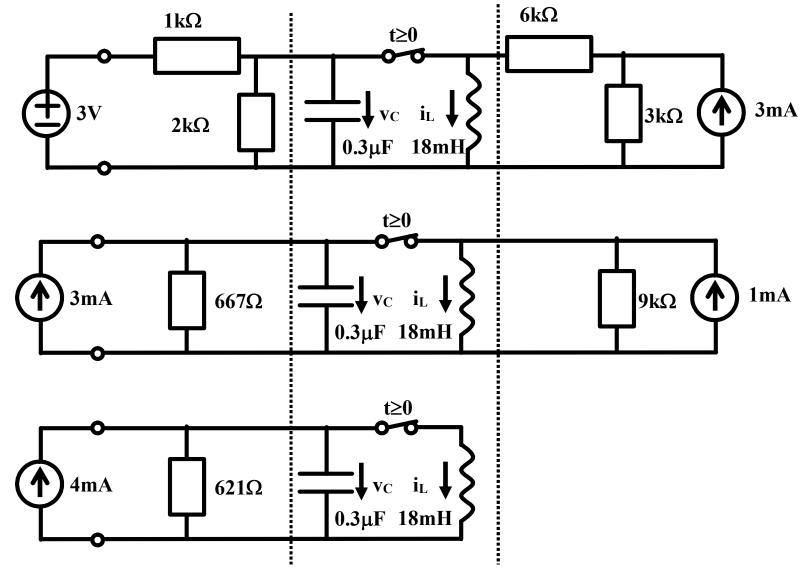
$$\xi > 1$$

#### 例1

■ 开关在t=0时刻闭合。开关闭合前电路已经稳定。求开关闭合后, 电容电压v<sub>C</sub>(t)和电感电流i<sub>L</sub>(t)的变化规律

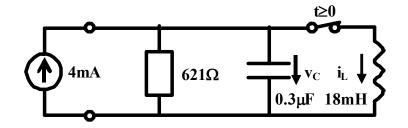


### RLC并联



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## i要素:阻尼系数和自由振荡频率



串联RLC

$$\omega_0 = \frac{1}{\sqrt{LC}}$$

$$\omega_0 = \frac{1}{\sqrt{CL}} = \frac{1}{\sqrt{LC}}$$

$$Z_0 = \sqrt{\frac{L}{C}} = \omega_0 L = \frac{1}{\omega_0 C}$$

$$Z_0 = \sqrt{\frac{L}{C}} = \omega_0 L = \frac{1}{\omega_0 C} \qquad Y_0 = \sqrt{\frac{C}{L}} = \omega_0 C = \frac{1}{\omega_0 L}$$

$$Q = \frac{Z_0}{R} = \frac{虚功}{宴功}$$

$$Q = \frac{Y_0}{G} = \frac{虚功}{实功}$$

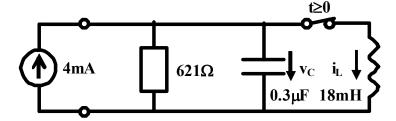
$$\xi = \frac{1}{2Q} = \frac{R}{2Z_0}$$

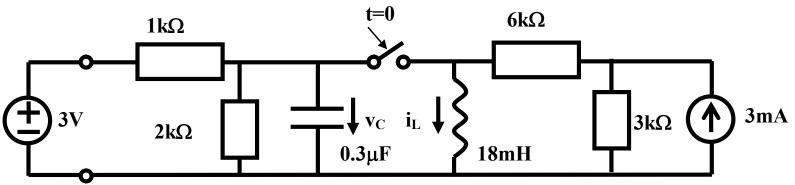
$$\xi = \frac{1}{2Q} = \frac{G}{2Y_0}$$

$$\omega_0 = \frac{1}{\sqrt{LC}} = \frac{1}{\sqrt{18m \times 0.3\mu}}$$
$$= 13.6 krad/s$$

$$\xi = \frac{G}{2Y_0} = \frac{1}{2R} \sqrt{\frac{L}{C}}$$
$$= \frac{1}{2 \times 621} \sqrt{\frac{18m}{0.3\mu}} = 0.1973$$

### 五要素:两个初值





$$v_C(0^-) = \frac{2k\Omega}{1k\Omega + 2k\Omega} \times 3V = 2V$$

$$i_L(0^-) = \frac{3k\Omega}{6k\Omega + 3k\Omega} \times 3mA = 1mA$$

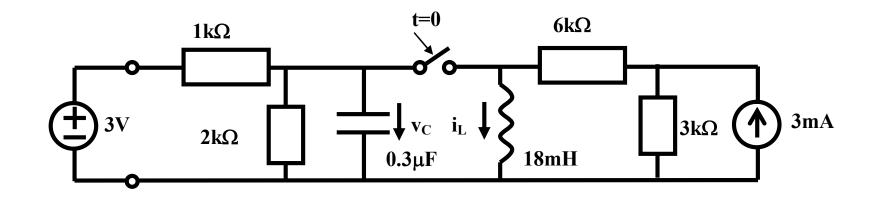
$$v_C(0^+) = v_C(0^-) = 2V$$

$$i_L(0^+) = i_L(0^-) = 1mA$$

$$\frac{dv_{C}(0^{+})}{dt} = \frac{1}{C}i_{C}(0^{+}) = \frac{1}{C}(i_{S}(0^{+}) - i_{L}(0^{+}) - i_{R}(0^{+})) = \frac{1}{C}\left(4mA - 1mA - \frac{v_{C}(0^{+})}{R}\right)$$

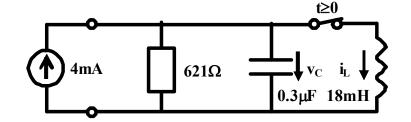
$$= \frac{1}{0.3\mu F}\left(4mA - 1mA - \frac{2V}{621\Omega}\right) = -\frac{0.2222mA}{0.3\mu F} = -0.7407V/ms$$

### 五要素: 稳态响应



$$v_{C,\infty}(t) = 0$$

$$v_{C,\infty}(0^+) = 0$$



$$\frac{dv_{C,\infty}(0^+)}{dt} = 0$$

### 五要素解

$$\begin{split} &v_{C}(t) = v_{C,\infty}(t) + \left(V_{0} - V_{\infty,0}\right)e^{-\xi\omega_{0}t}\cos\left(\sqrt{1-\xi^{2}}\,\omega_{0}t\right) \\ &+ \left(V_{0} - V_{\infty,0} + \frac{\dot{V}_{0} - \dot{V}_{\infty,0}}{\xi\omega_{0}}\right) \frac{\xi}{\sqrt{1-\xi^{2}}}e^{-\xi\omega_{0}t}\sin\left(\sqrt{1-\xi^{2}}\,\omega_{0}t\right) \\ &= 0 + (2-0)e^{-\xi\omega_{0}t}\cos\left(\sqrt{1-\xi^{2}}\,\omega_{0}t\right) \\ &+ \left(2-0 + \frac{-0.7407\times10^{3} - 0}{0.1973\times13.6\times10^{3}}\right) \frac{\xi}{\sqrt{1-\xi^{2}}}e^{-\xi\omega_{0}t}\sin\left(\sqrt{1-\xi^{2}}\,\omega_{0}t\right) \\ &= 2e^{-\xi\omega_{0}t}\cos\left(\sqrt{1-\xi^{2}}\,\omega_{0}t\right) + 1.7241 \frac{\xi}{\sqrt{1-\xi^{2}}}e^{-\xi\omega_{0}t}\sin\left(\sqrt{1-\xi^{2}}\,\omega_{0}t\right) \\ &= 2e^{-\frac{t}{0.3724\times10^{-3}}}\cos\left(13.34\times10^{3}t\right) + 0.347e^{-\frac{t}{0.3724\times10^{-3}}}\sin\left(13.34\times10^{3}t\right) \\ &= 2.03e^{-\frac{t}{0.3724\times10^{-3}}}\sin\left(13.34\times10^{3}t + 1.4\right) \quad \text{幅度指数衰减的正弦振荡波形} \end{split}$$

## 欠阻尼减幅振荡

$$0 < \xi < 1$$

$$Q = \frac{1}{2\xi} > 0.5$$

$$x(t) = x_{\infty}(t) + e^{-\xi\omega_{0}t} \left(A\cos\sqrt{1-\xi^{2}}\omega_{0}t + B\sin\sqrt{1-\xi^{2}}\omega_{0}t\right)$$
 $= x_{\infty}(t) + \sqrt{A^{2} + B^{2}}e^{-\xi\omega_{0}t}\cos\left(\sqrt{1-\xi^{2}}\omega_{0}t - \arctan\frac{B}{A}\right)$ 
 $= x_{\infty}(t) + \sqrt{A^{2} + B^{2}}e^{-\frac{t}{\tau}}\cos(\omega_{d}t - \varphi_{0})$ 
 $\tau = \frac{1}{\xi\omega_{0}}$ 
幅度指数衰減的正弦振荡波形:振铃

$$e^{-\xi\omega_0 t} \left| t = QT = e^{-\frac{\xi}{\sqrt{1-\xi^2}}\sqrt{1-\xi^2}\omega_0 QT} \right| = e^{-\frac{\pi}{\sqrt{1-\xi^2}}} < e^{-\pi} = 0.043 = 4.3\%$$

$$e^{-\xi\omega_0 t}$$
  $t = 1.5QT = e^{-1.5\frac{\xi}{\sqrt{1-\xi^2}}\sqrt{1-\xi^2}\omega_0 QT} = e^{-\frac{1.5\pi}{\sqrt{1-\xi^2}}} < e^{-1.5\pi} = 0.009 = 0.9\%$ 

经过Q个周期,振铃幅度衰减为4.3%以下 经过1.5Q个周期,振铃幅度衰减为1%以下 经过2.2Q个周期,振铃幅度衰减为0.1%以下

## 无阻尼等幅振荡 无阻尼等幅振荡

$$x(t) = x_{\infty}(t) + (X_{0} - X_{\infty 0})e^{-\xi\omega_{0}t}\cos\sqrt{1 - \xi^{2}}\omega_{0}t$$

$$+ \left(X_{0} - X_{\infty 0} + \frac{\dot{X}_{0} - \dot{X}_{\infty 0}}{\xi\omega_{0}}\right)\frac{\xi}{\sqrt{1 - \xi^{2}}}e^{-\xi\omega_{0}t}\sin\sqrt{1 - \xi^{2}}\omega_{0}t$$

$$x(t) = x_{\infty}(t) + (X_{0} - X_{\infty 0})\cos\omega_{0}t + \frac{\dot{X}_{0} - \dot{X}_{\infty 0}}{\omega_{0}}\sin\omega_{0}t \qquad \xi = 0$$

$$= x_{\infty}(t) + \sqrt{(X_{0} - X_{\infty 0})^{2} + (\frac{\dot{X}_{0} - \dot{X}_{\infty 0}}{\omega_{0}})^{2}}\cos\left(\omega_{0}t - \arctan\frac{\dot{X}_{0} - \dot{X}_{\infty 0}}{\omega_{0}(X_{0} - X_{\infty 0})}\right)$$

无阻尼:振荡幅度不变 LC自由振荡频率:无阻尼振荡频率

## 无阻尼LC谐振腔的自由振荡

稳态响应由源决定,本例无外加激励源(自由振荡)

$$v_{C\infty}(t)=0$$

$$i_{L\infty}(t)=0$$

$$v_C(0^+) = v_C(0^-) = V_0$$

$$i_L(0^+) = i_L(0^-) = I_0$$

$$\frac{d}{dt}v_{C}(0^{+}) = \frac{i_{C}(0^{+})}{C} \qquad \frac{d}{dt}i_{L}(0^{+}) = \frac{v_{L}(0^{+})}{L} 
= -\frac{i_{L}(0^{+})}{C} = -\frac{i_{L}(0^{-})}{C} \qquad = \frac{v_{C}(0^{+})}{L} = \frac{v_{C}(0^{-})}{L} 
= -\frac{I_{0}}{L} = \frac{V_{0}}{L}$$

$$\frac{d}{dt}i_{L}(0^{+}) = \frac{v_{L}(0^{+})}{L}$$

$$= \frac{v_{C}(0^{+})}{L} = \frac{v_{C}(0^{-})}{L}$$

$$= \frac{V_{0}}{L}$$

$$\begin{aligned} v_C(t) &= v_{C\infty}(t) + (V_{C0} - V_{C\infty0})\cos\omega_0 t + \frac{\dot{V}_{C0} - \dot{V}_{C\infty0}}{\omega_0}\sin\omega_0 t \\ &= 0 + V_0\cos\omega_0 t - \frac{I_0}{\omega_0 C}\sin\omega_0 t = V_0 \sqrt{1 + \frac{LI_0^2}{CV_0^2}\cos\left(\omega_0 t + \arctan\frac{Z_0I_0}{V_0}\right)} \end{aligned}$$

 $\xi = 0$   $\omega_0 = \frac{1}{\sqrt{G}}$ 

## 无阻尼LC谐振腔的自由振荡

$$C = \begin{cases} i_L(t) \\ \downarrow v_C(t) \end{cases} L$$

$$\omega_0 = \frac{1}{\sqrt{LC}} \qquad Z_0 = \sqrt{\frac{L}{C}}$$

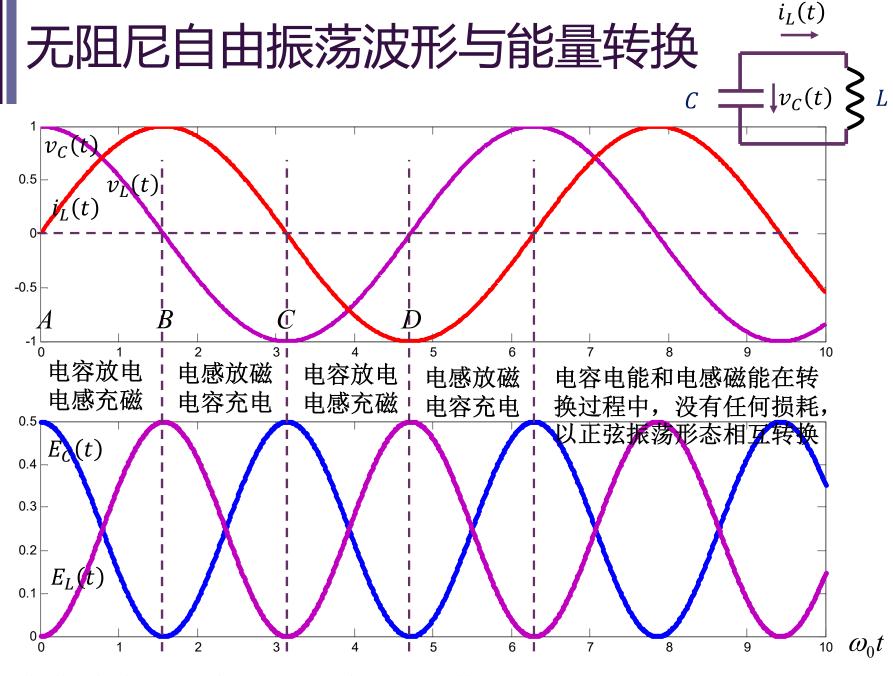
$$v_C(t) = V_0 \cos \omega_0 t - \frac{I_0}{\omega_0 C} \sin \omega_0 t = V_0 \sqrt{1 + \frac{LI_0^2}{CV_0^2} \cos\left(\omega_0 t + \arctan\frac{Z_0 I_0}{V_0}\right)}$$

$$i_L(t) = I_0 \cos \omega_0 t + \frac{V_0}{\omega_0 L} \sin \omega_0 t = I_0 \sqrt{1 + \frac{CV_0^2}{LI_0^2}} \sin \left(\omega_0 t + \arctan \frac{Z_0 I_0}{V_0}\right)$$

可以验证 
$$v_C(t) = v_L(t) = L \frac{d}{dt} i_L(t)$$
 满足元件约束方程

$$E(t) = E_C(t) + E_L(t) = \frac{1}{2}Cv_C^2(t) + \frac{1}{2}Li_L^2(t) = \frac{1}{2}CV_0^2 + \frac{1}{2}LI_0^2 = E(0)$$

无阻尼自由谐振时,电容电能和电感磁能以正弦规律无损失相互转换,谐振腔内总储能始终不变(振荡幅度不变,振荡幅度由初始储能决定)

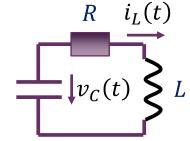


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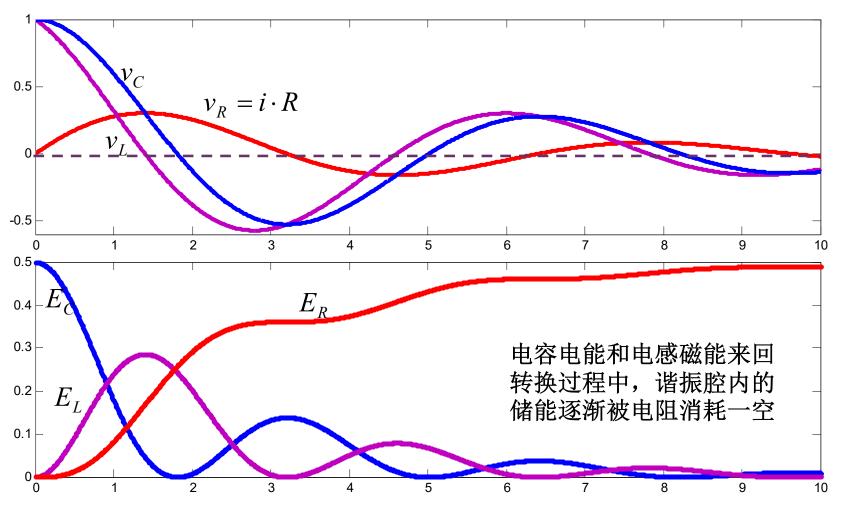
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11/6/2020

### 欠阻尼自由振荡波形与能量转换

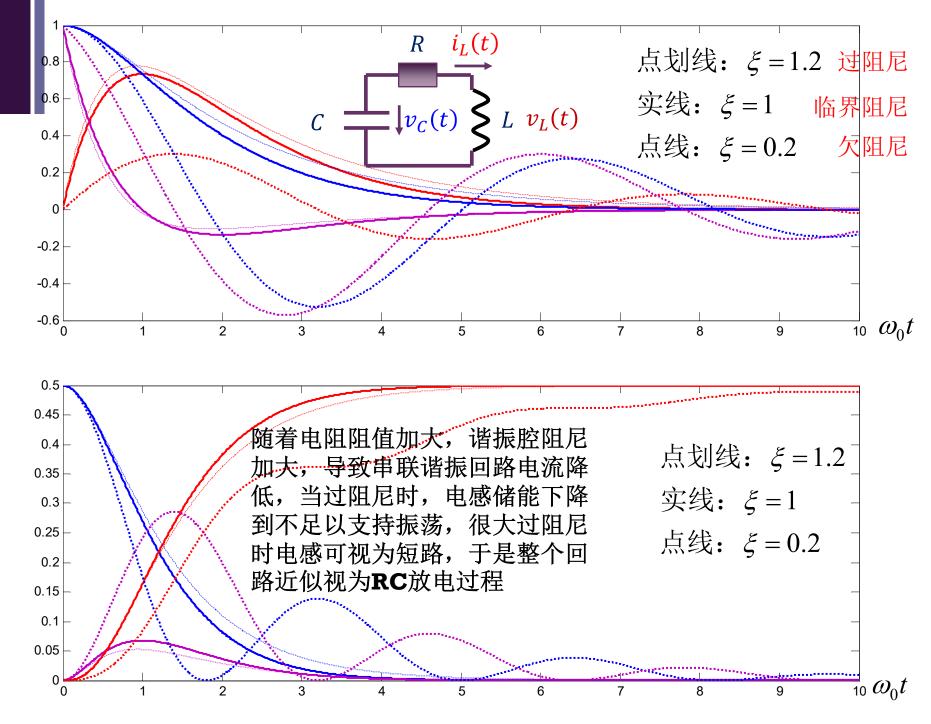


$$\xi = \frac{R}{2Z_0} = 0.2$$



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# 本节内容小结

#### ■ 描述一阶LTI系统的关键参量是时间常数τ

- 一阶系统特征根 $\lambda = -\frac{1}{\tau}$ : 指数衰减特性
- 一阶RC:  $\tau = RC$
- 一阶RL:  $\tau = GL$

### ■ 描述二阶LTI系统的关键参量是阻尼系数 $\xi$ 和自由振荡频率 $\omega_0$

- 二阶系统特征根 $\lambda_{1,2} = \left(-\xi \pm \sqrt{\xi^2 1}\right)\omega_0$ 
  - $\xi > 1$ : 过阻尼,两个不等负实根: 指数衰减特性
  - $\xi = 1$ : 临界阻尼,两个负实等根: 指数衰减特性(偏)
  - 0 < ξ < 1: 欠阻尼,两个共轭复根:幅度指数衰减的正弦振荡特性
  - $\xi = 0$ : 无阻尼,两个共轭纯虚根: 等幅正弦振荡特性

■ 串联RLC: 
$$\omega_0 = \frac{1}{\sqrt{LC}}$$
,  $\xi = \frac{R}{2Z_0}$ ,  $Z_0 = \omega_0 L = \frac{1}{\omega_0 C} = \sqrt{\frac{L}{C}}$ 

■ 并联RLC: 
$$\omega_0 = \frac{1}{\sqrt{LC}}$$
,  $\xi = \frac{G}{2Y_0}$ ,  $Y_0 = \omega_0 C = \frac{1}{\omega_0 L} = \sqrt{\frac{C}{L}}$ 

#### ■ n阶LTI系统的时域分析需要2n+1个要素

- 1个稳态响应
- n个初值
- n个特征根

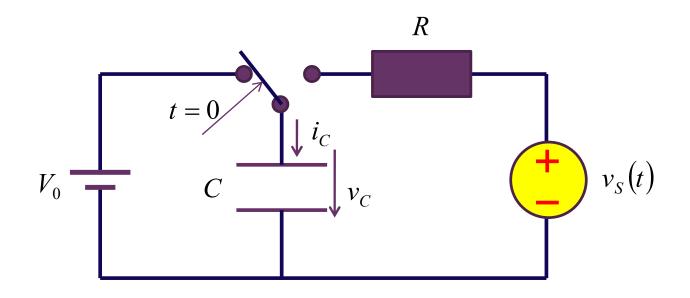
### 作业讲解: 有关稳态响应

- 三要素法和五要素法都有求稳态响应的需求
- 稳态响应指的是激励源在 $t = -\infty$ 时就将激励源加载到系统输入端导 致的系统响应
  - (1) 冲激激励,阶跃激励,直流激励: 等待足够长时间,均认为是直流 电路: 电容开路, 电感短路可获得直流激励下的稳态解
  - (2) 正弦波激励: 相量法(电容C用jωC导纳替代,电感L用jωL阻抗替 代)可获得正弦激励下的稳态解
  - (3) 方波激励: 分时段阶跃激励
  - (4) 其他激励: 稳态响应形式应当和激励形态相类似, 猜测稳态响应解 的形态,代入到原始方程中验证,确定猜测形态中的系数

一阶系统的稳态响应不妨用理论表达式验证一下

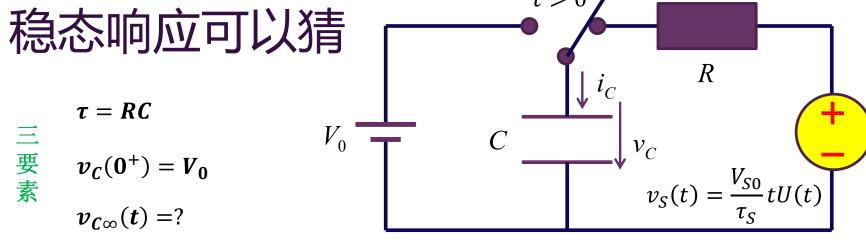
$$x_{\infty}(t) = \int_{-\infty}^{t} e^{\frac{\lambda - t}{\tau}} s(\lambda) d\frac{\lambda}{\tau}$$

### 作业6.7 稳态响应



$$v_S(t) = \frac{V_{S0}}{\tau_S}t$$

假设激励源是一个斜升信号,请用三要素法给出电容电压表达式。



稳态响应可以猜: 稳态响应和激励具有相同的形态, 同时电容充放电有滞后效应, 猜测为

$$v_{C\infty}(t) = \alpha(t - \tau_0)$$

稳态响应必然满足电路方程,因此可通过代入电路方程确认两个待定参量

$$v_{S}(t) = v_{R}(t) + v_{C}(t) = RC \frac{d}{dt} v_{C}(t) + v_{C}(t)$$

$$\frac{V_{S0}}{\tau_{S}} t = v_{S\infty}(t) = RC \frac{d}{dt} v_{C\infty}(t) + v_{C\infty}(t) = RC\alpha + \alpha t - \alpha \tau_{0}$$

$$\alpha = \frac{V_{S0}}{\tau_{S}} \qquad \tau_{0} = RC = \tau \qquad v_{C\infty}(t) = \frac{V_{S0}}{\tau_{S}} (t - \tau)$$

故而电容电压为

$$v_{\mathcal{C}}(t) = \frac{V_{S0}}{\tau_{\mathcal{S}}}(t-\tau) + \left(V_{0} + \frac{\tau}{\tau_{\mathcal{S}}}V_{S0}\right)e^{-\frac{t}{\tau}} \qquad (t>0)$$

### 稳态响应也可以推衍出

零输入响应都是一样的,不一样的是零状态响应,完全由源决定

$$v_S(t) = V_{S0}U(t)$$
  $\longrightarrow$   $v_{C,ZSR}(t) = V_{S0}g(t) = V_{S0}(1 - e^{-\frac{t}{\tau}})U(t)$ 

由线性时不变系统特性:激励积分,响应也积分

$$v_{S}(t) = \frac{V_{S0}}{\tau_{S}} t U(t) \longrightarrow v_{C,ZSR}(t) = \frac{1}{\tau_{S}} \int_{-\infty}^{t} V_{S0} g(\lambda) d\lambda$$

$$= \frac{1}{\tau_{S}} \int_{-\infty}^{t} V_{S0} U(\lambda) d\lambda$$

$$= \frac{1}{\tau_{S}} \int_{-\infty}^{t} V_{S0} \left(1 - e^{-\frac{\lambda}{\tau}}\right) U(\lambda) d\lambda$$

$$= \frac{V_{S0}}{\tau_{S}} \int_{0}^{t} \left(1 - e^{-\frac{\lambda}{\tau}}\right) d\lambda = \frac{V_{S0}}{\tau_{S}} \left(\lambda + \tau e^{-\frac{\lambda}{\tau}}\right) \begin{vmatrix} t \\ 0 \end{vmatrix}$$

$$= \frac{V_{S0}}{\tau_{S}} \left(t + \tau e^{-\frac{t}{\tau}} - \tau\right)$$

$$v_{C}(t) = v_{C,ZSR}(t) + v_{C,ZIR}(t) = \frac{V_{S0}}{\tau_{S}} \left( t + \tau e^{-\frac{t}{\tau}} - \tau \right) + V_{0} e^{-\frac{t}{\tau}}$$

$$= \frac{V_{S0}}{\tau_{S}} (t - \tau) + \left( \frac{V_{S0}}{\tau_{S}} \tau + V_{0} \right) e^{-\frac{t}{\tau}} \qquad (t > 0)$$

### 两个零状态响应的对比

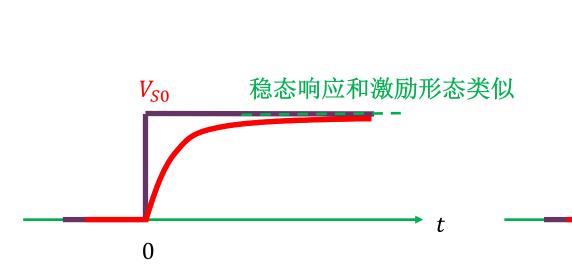
### 阶跃响应与斜升响应

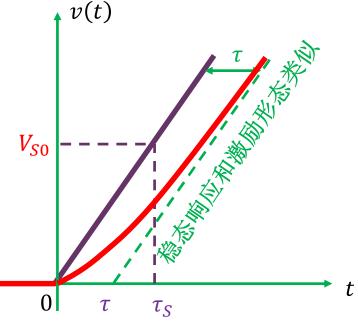
$$v_{S}(t) = V_{S0}U(t)$$

$$v_S(t) = \frac{V_{S0}}{\tau_S} t U(t)$$

$$v_{C,ZSR}(t) = V_{S0} \left(1 - e^{-\frac{t}{\tau}}\right) U(t)$$

$$v_{C,ZSR}(t) = \frac{V_{S0}}{\tau_S}(t-\tau) + \frac{\tau}{\tau_S}V_{S0}e^{-\frac{t}{\tau}}$$





(t > 0)

# 不妨代入理论表达式验证一番

$$v_{C}(t) = V_{0} \cdot e^{-\frac{t}{\tau}} + \int_{0}^{t} v_{S}(\lambda) \cdot e^{\frac{\lambda - t}{\tau}} d\frac{\lambda}{\tau} = v_{C\infty}(t) + (V_{0} - v_{C\infty}(0)) \cdot e^{-\frac{t}{\tau}}$$

$$(t \ge 0)$$

何谓稳态?瞬态结束即为稳态! 如何结束瞬态?开关启动时间退至-∞!

稳态响应 
$$v_{C\infty}(t) = \int_{-\infty}^{t} v_S(\lambda) \cdot e^{\frac{\lambda - t}{\tau}} d\frac{\lambda}{\tau}$$

$$v_{C\infty}(t) = \int_{-\infty}^{t} v_{S}(\lambda) e^{\frac{\lambda - t}{\tau}} d\frac{\lambda}{\tau} = \int_{-\infty}^{t} \frac{V_{S0}}{\tau_{S}} \lambda e^{\frac{\lambda - t}{\tau}} d\frac{\lambda}{\tau} = \frac{V_{S0}}{\tau_{S}} e^{-\frac{t}{\tau}} \int_{-\infty}^{t} \lambda e^{\frac{\lambda}{\tau}} d\frac{\lambda}{\tau}$$

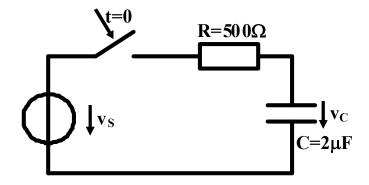
$$= \frac{V_{S0}}{\tau_{S}} e^{-\frac{t}{\tau}} \int_{-\infty}^{t} \lambda de^{\frac{\lambda}{\tau}} = \frac{V_{S0}}{\tau_{S}} e^{-\frac{t}{\tau}} \left(\lambda e^{\frac{\lambda}{\tau}} - \int_{-\infty}^{t} e^{\frac{\lambda}{\tau}} d\lambda\right) = \frac{V_{S0}}{\tau_{S}} e^{-\frac{t}{\tau}} \left(\lambda e^{\frac{\lambda}{\tau}} - \tau e^{\frac{\lambda}{\tau}}\right) \Big|_{-\infty}^{t}$$

$$= \frac{V_{S0}}{\tau_{S}} e^{-\frac{t}{\tau}} \left(t e^{\frac{t}{\tau}} - \tau e^{\frac{t}{\tau}}\right) = \frac{V_{S0}}{\tau_{S}} (t - \tau)$$

$$v_C(t) = \frac{V_{S0}}{\tau_S}(t - \tau) + \left(V_0 + \frac{\tau}{\tau_S}V_{S0}\right)e^{-\frac{t}{\tau}} \qquad (t > 0)$$

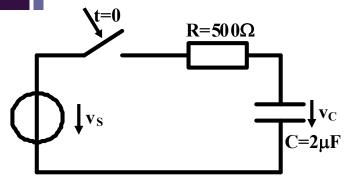
# 作业7.3 三要素法求解正弦激励

- 如图所示,t=0时刻开关闭合,正弦波电压激励源加载到一阶RC串 联电路端口
  - $v_S(t) = 2\cos\omega_0 t$ ■其中,  $\omega_0 = 2\pi f_0 \qquad f_0 = 500Hz$
- 假设电容初始电压为0, V<sub>C</sub>(0)=0, 请给出电容电压时域表达式



### 三要素法之稳态响应

### 相量法求正弦稳态响应



$$\tau = RC = 1ms$$

$$v_C(0^+) = 0$$

$$v_{c\infty}(t) = ?$$

$$v_S(t) = 2\cos\omega_0 t$$
  $\omega_0 = 2\pi f_0$   $f_0 = 500Hz$ 

$$\dot{V}_{C} = \frac{1}{1 + j\omega_{0}RC}\dot{V}_{S} = \frac{1}{1 + j\times 2\pi \times f_{0} \times R \times C}\dot{V}_{S}$$

$$\dot{V}_{C} = \frac{1}{1 + j\times 2\pi \times 500 \times 500 \times 0.000002} \times 2 = \frac{1}{1 + j3.1416}\dot{V}_{C}$$

$$\dot{V}_{C} = \frac{1}{j\omega_{0}C}\dot{V}_{S} = \frac{1}{1 + j\omega_{0}RC}\dot{V}_{S}$$

$$\dot{V}_{C} = \frac{1}{j\omega_{0}C}\dot{V}_{S} = \frac{1}{1 + j\omega_{0}RC}\dot{V}_{S}$$

$$= \frac{1}{1 + j\times 2\pi \times 500 \times 500 \times 0.000002} \times 2 = \frac{2}{1 + j3.1416}$$

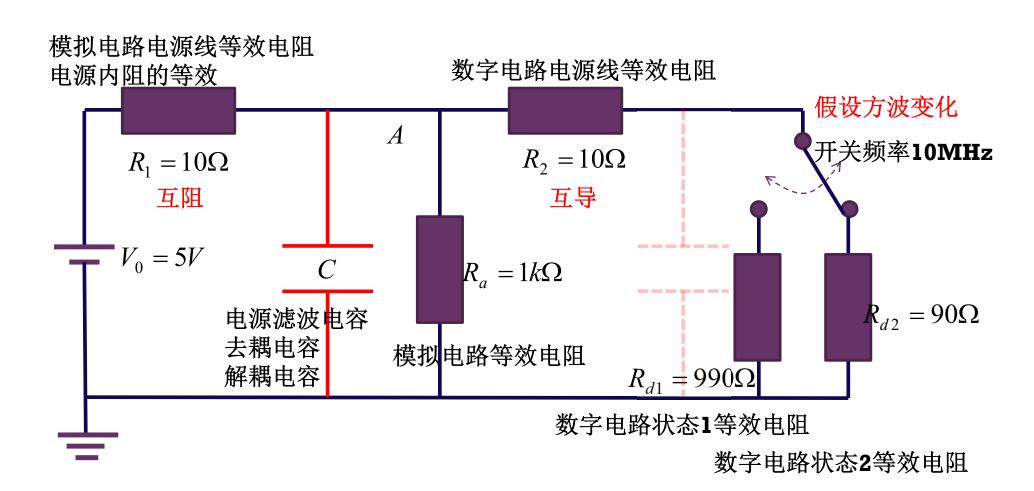
$$= 0.6066e^{-j72.34^{\circ}}$$

$$v_{c\infty}(t) = 0.6066\cos(\omega_0 t - 72.34^\circ)$$

$$v_C(t) = v_{C_{\infty}}(t) + \left(v_C(0^+) - v_{C_{\infty}}(0^+)\right)e^{-\frac{t}{\tau}} = 0.6066\cos(\omega_0 t - 72.34^\circ) - 0.1840e^{-\frac{t}{\tau}}$$

### 作业7.6 用电容做电源滤波(选作)

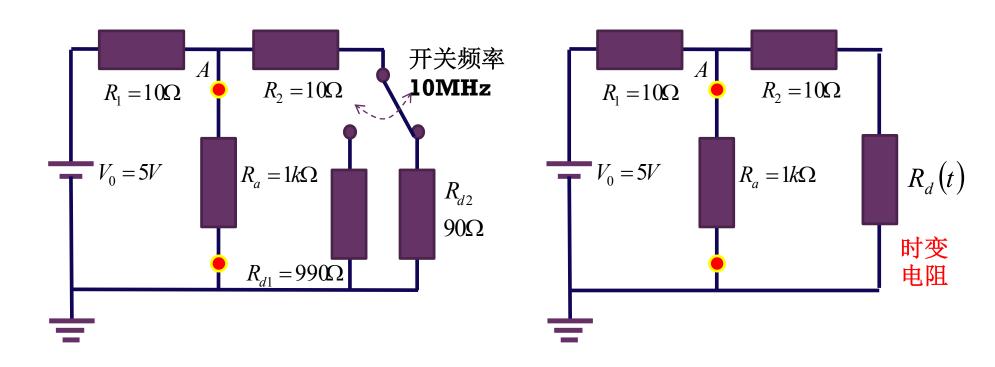
- 1) 假设没有滤波电容,求模拟电路电源端A点的电压波形
- 2) 多大的电容,可以使得A点电压波形起伏是没有电容时的1/10



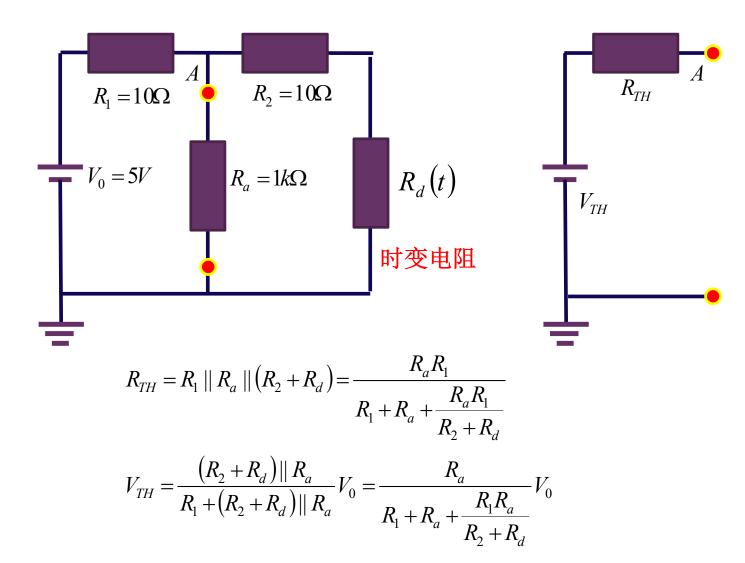
### 将数字芯片抽象为时变电阻

$$R_d(t) = R_{d1}S_1(t) + R_{d2}(1 - S_1(t))$$

$$S_1(t)$$
  $0$   $0.1 \mu s$ 

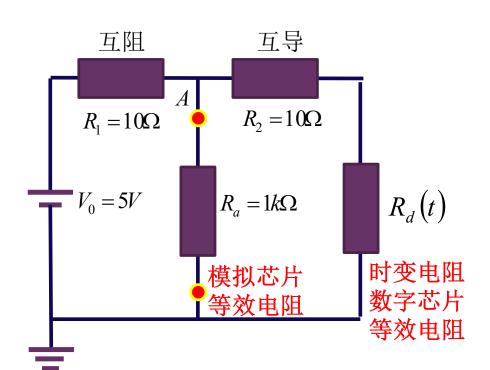


# 对模拟芯片的电源-地端口做戴维南等效



### |互阻和互导 形成芯片间的串扰

$$R_{TH} = R_1 || R_a || (R_2 + R_d) = \frac{R_a R_1}{R_1 + R_a + \frac{R_a R_1}{R_2 + R_d}}$$



$$V_{TH} = \frac{\left(R_2 + R_d\right) || R_a}{R_1 + \left(R_2 + R_d\right) || R_a} V_0 = \frac{R_a}{R_1 + R_a + \frac{R_1 R_a}{R_2 + R_d}} V_0$$

$$R_{TH} = 0$$

$$V_{TH} = V$$

如果没有互阻(互阻  $R_1=0$ ),AG端口等效 为恒压源,数字芯片的 时变电阻  $R_{l}=0$  变化(时变电阻 $\mathbf{R_d}$ )无 数字芯片  $V_{TH}=V_0$  注影响檔扣芯片中压 法影响模拟芯片电压

互阻 $\mathbf{R}_1$ 和互导 $\mathbf{G}_2$ 导致数字芯片 和模拟芯片相互耦合, 数字芯 片的电流变化导致模拟芯片电 源电压波动:不开避免的串扰

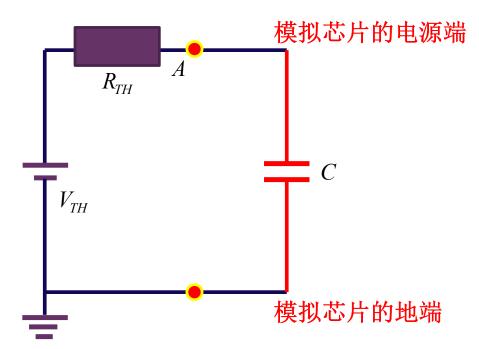
- (1) 电源内阻不为0
- (2) 无法为每个芯片单独供电

$$R_{TH} \stackrel{R_2 = \infty}{=} \frac{R_a R_1}{R_1 + R_a}$$

$$V_{TH} \stackrel{R_2 = \infty}{=} \frac{R_a}{R_1 + R_a} V_0$$

 $R_{TH} = \frac{R_a R_1}{R_1 + R_a}$  如果没有互导( $G_2 = 0$ ,分别单独提供供电电源),AG端口等 效源电压和源内阻均不受数字 芯片(时变电阻R<sub>4</sub>)的影响, 即数字芯片的电流变化无法影 响模拟芯片的电源电压

# 滤波电容 降低波动去耦电容 解除耦合



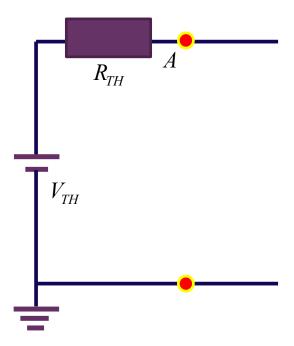
电容C具有电压保持功能, 具有求平均功能,只要电 容足够大, $V_{TH}$ 的变化就 会被电容抹平: 电源滤波, 芯片解耦

$$R_{TH}(t) = \frac{R_a R_1}{R_1 + R_a + \frac{R_a R_1}{R_2 + R_a(t)}}$$

$$V_{TH}(t) = \frac{R_a}{R_1 + R_a + \frac{R_1 R_a}{R_2 + R_d(t)}} V_0$$

数字芯片的电流变化用时 变电阻 $R_d(t)$ 抽象, $R_d(t)$ 对模拟芯片的影响通过互 阻、互导实现

### 未加去耦电容时的串扰情况



$$R_{TH1} = 9.804\Omega$$

$$R_{TH2} = 9.010\Omega$$

#### 等效内阻同时变化

$$R_{TH}(t) = \frac{R_a R_1}{R_1 + R_a + \frac{R_a R_1}{R_2 + R_d(t)}}$$

$$R_{TH}(t) = \frac{R_a R_1}{R_1 + R_a + \frac{R_a R_1}{R_2 + R_d(t)}} \qquad V_{TH}(t) = \frac{R_a}{R_1 + R_a + \frac{R_1 R_a}{R_2 + R_d(t)}} V_0$$

$$R_d(t) = R_{d1}S_1(t) + R_{d2}(1 - S_1(t))$$

$$V_{TH,1}(t) = \frac{R_a}{R_1 + R_a + \frac{R_1 R_a}{R_2 + R_{d1}}} V_0 \qquad V_{TH,2}(t) = \frac{R_a}{R_1 + R_a + \frac{R_1 R_a}{R_2 + R_{d2}}} V_0$$

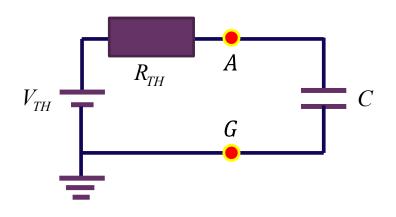
$$= \frac{1000}{10 + 1000 + \frac{10 \cdot 1000}{10 + 990}} \times 5 \qquad = \frac{1000}{10 + 1000 + \frac{10 \cdot 1000}{10 + 90}} \times 5$$

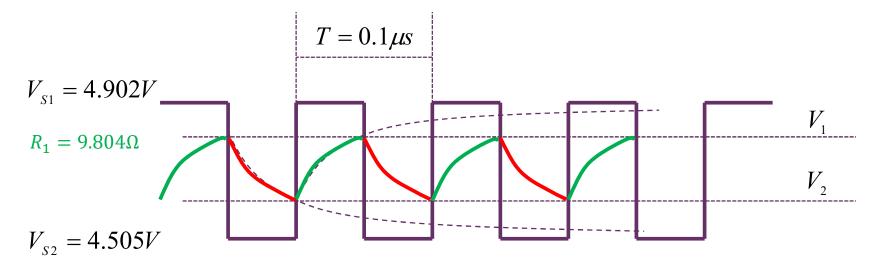
$$= \frac{1000}{10 + 1000 + \frac{10}{10}} \times 5 \qquad = \frac{1000}{10 + 1000 + \frac{100}{10}} \times 5$$

$$= 4.902V \qquad = 4.505V$$

$$\Delta V_{A0} = 4.902 - 4.505 = 0.397V$$
 电压波动**0.4V**

### 去耦电容使得串扰幅度降低



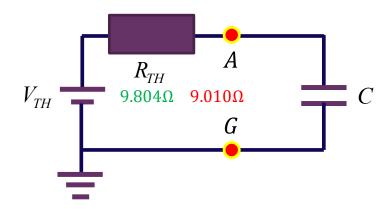


$$R_2 = 9.010\Omega$$

$$R_2 = 9.010\Omega$$
  $\Delta V_{A0} = 0.397V$ 

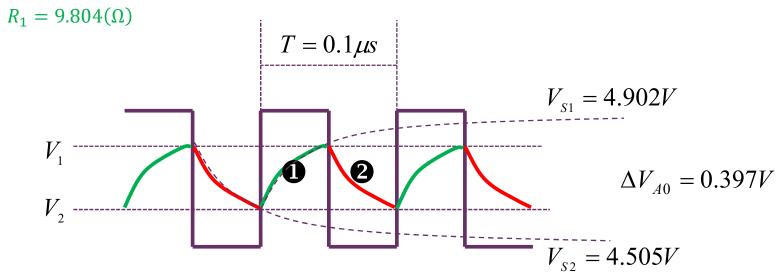
$$\Delta V_A = V_1 - V_2 \le 0.1 \Delta V_{A0} = 0.0397V$$

### 充放电抑制突变



$$\mathbf{0} \qquad v_r(t) = V_{S1} + (V_2 - V_{S1})e^{-\frac{\Delta t_1}{\tau_1}} \qquad \qquad \tau_1 = R_1 C$$

$$\tau_{_1}=R_{_1}C$$



$$\Delta V_A = V_1 - V_2 \le 0.1 \Delta V_{A0} = 0.0397V$$

$$v_f(t) = V_{S2} + (V_1 - V_{S2})e^{-\frac{\Delta t_2}{\tau_2}}$$

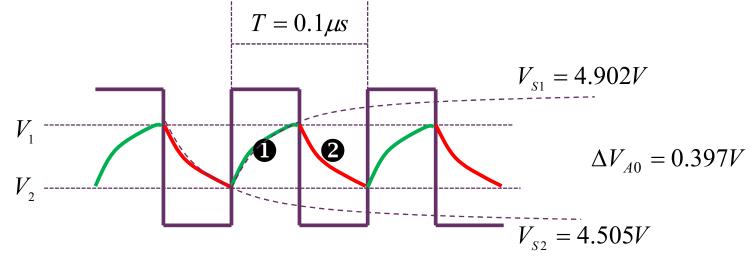
$$\tau_2 = R_2 C$$

$$R_2 = 9.010(\Omega)$$

### 电容使得波动变小了

 $R_1 = 9.804(\Omega)$ 

 $R_2 = 9.010(\Omega)$ 



$$v_r(t) = V_{S1} + (V_2 - V_{S1})e^{-\frac{\Delta t_1}{\tau_1}}$$

$$V_1 = V_{S1} + (V_2 - V_{S1})e^{-\frac{0.5T}{\tau_1}}$$

$$\tau_{_1}=R_{_1}C$$

$$\tau_2 = R_2 C$$

$$v_{f}(t) = V_{S2} + (V_{1} - V_{S2})e^{-\frac{\Delta t_{2}}{\tau_{2}}}$$

$$V_{2} = V_{S2} + (V_{1} - V_{S2})e^{-\frac{0.5T}{\tau_{2}}}$$

$$\Delta V = V_1 - V_2 \le 0.1 \Delta V_S$$

$$T=0.1\mu s$$

$$C = ?$$

# 电容如何取值达到要求?

$$V_{1} = V_{S1} + (V_{2} - V_{S1})e^{\frac{0.5T}{r_{1}}} = V_{2}a_{1} + V_{S1}(1 - a_{1})$$

$$a_{1} = e^{\frac{0.5T}{r_{1}}}$$

$$V_{2} = V_{S2} + (V_{1} - V_{S2})e^{\frac{0.5T}{r_{2}}} = V_{1}a_{2} + V_{S2}(1 - a_{2})$$

$$a_{2} = e^{\frac{0.5}{r_{1}}}$$

$$V_{1} - V_{2}a_{1} = V_{S1}(1 - a_{1})$$

$$V_{1} = \frac{V_{S1}(1 - a_{1}) + V_{S2}(1 - a_{2})a_{1}}{1 - a_{1}a_{2}}$$

$$V_{2} - V_{1}a_{2} = V_{S2}(1 - a_{2})$$

$$V_{2} = \frac{V_{S2}(1 - a_{2}) + V_{S1}(1 - a_{1})a_{2}}{1 - a_{1}a_{2}}$$

$$\Delta V_{A} = V_{1} - V_{2} = (V_{S1} - V_{S2})\frac{(1 - a_{1})(1 - a_{2})}{1 - a_{1}a_{2}} \le 0.1(V_{S1} - V_{S2})$$

$$\frac{(1 - a_{1})(1 - a_{2})}{1 - a_{1}a_{2}} \le 0.1$$
需要求解非线性方程获得电容C大小

$$a_1 = e^{\frac{-0.5T}{\tau_1}}$$
  $a_2 = e^{\frac{-0.5T}{\tau_2}}$   $\tau_1 = R_1 C$   $\tau_2 = R_2 C$   $T = 0.1 \mu s$  11/6/2020

# 保留主项获得足够精确的近似解

$$\frac{\left(1-a_1\right)\left(1-a_2\right)}{1-a_1a_2} \le 0.1$$

$$a_1 = e^{-\frac{0.5T}{R_1C}}$$

$$a_1 = e^{-\frac{0.5T}{R_1C}}$$
  $a_2 = e^{-\frac{0.5T}{R_2C}}$ 

假设C足够大,时间常数足够大, 充放电时间足够长,可以做如下估算:

$$a_1 = e^{-\frac{0.5T}{R_1C}} \approx 1 - \frac{0.5T}{R_1C}$$
  $a_2 = e^{-\frac{0.5T}{R_2C}} \approx 1 - \frac{0.5T}{R_2C}$ 

$$a_2 = e^{-\frac{0.5T}{R_2C}} \approx 1 - \frac{0.5T}{R_2C}$$

$$0.1 \ge \frac{(1-a_1)(1-a_2)}{1-a_1a_2} \approx \frac{\frac{0.5T}{\tau_1} \frac{0.5T}{\tau_2}}{\frac{0.5T}{\tau_1} + \frac{0.5T}{\tau_2} - \frac{0.5T}{\tau_1} \frac{0.5T}{\tau_2}} \approx \frac{\frac{0.5T}{\tau_1} \frac{0.5T}{\tau_2}}{\frac{0.5T}{\tau_1} + \frac{0.5T}{\tau_2}} = \frac{0.5T}{\tau_1 + \tau_2} = \frac{0.5T}{C(R_1 + R_2)}$$

$$C \ge \frac{0.5T}{0.1(R_1 + R_2)} = \frac{5T}{R_1 + R_2} = \frac{5 \times 0.1 \mu s}{9.8 + 9.0} = 0.0266 \mu F$$

# 验算设计正确性

$$\tau_1 = R_1 C = 9.8 \times 0.03 \mu F = 0.294 \mu s$$

验证正确性 
$$\tau_1 = R_1 C = 9.8 \times 0.03 \mu F = 0.294 \mu S$$
  $\tau_2 = R_2 C = 9.0 \times 0.03 \mu F = 0.270 \mu S$ 

$$a_1 = e^{\frac{0.5T}{\tau_1}} = e^{\frac{0.05}{0.294}} = e^{-0.1701} = 0.847$$

$$a_1 = e^{\frac{-0.5T}{\tau_1}} = e^{\frac{-0.05}{0.294}} = e^{-0.1701} = 0.847$$
  $a_2 = e^{\frac{-0.5T}{\tau_2}} = e^{\frac{-0.05}{0.270}} = e^{-0.1852} = 0.831$ 

$$V_{1} = \frac{V_{S1}(1 - a_{1}) + V_{S2}(1 - a_{2})a_{1}}{1 - a_{1}a_{2}} = \frac{4.902 \times 0.153 + 4.505 \times 0.169 \times 0.847}{0.296} = 4.712V$$

$$V_2 = \frac{V_{S2}(1 - a_2) + V_{S1}(1 - a_1)a_2}{1 - a_1a_2} = \frac{4.505 \times 0.169 + 4.902 \times 0.153 \times 0.831}{0.296} = 4.678V$$

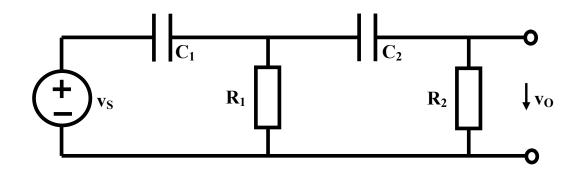
$$\Delta V_A = V_1 - V_2 = 4.712 - 4.678 = 0.034V$$
  $\Delta V_{A0} = 4.902 - 4.505 = 0.397V$ 

$$\Delta V_{40} = 4.902 - 4.505 = 0.397V$$

确实满足  $\Delta V_A \leq 0.1 V_{A0}$ 

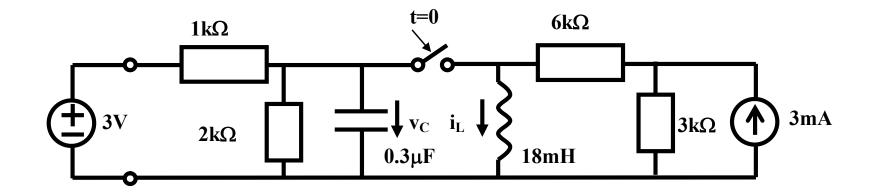
 $C=0.3\mu F$ , $\Delta V<0.01\Delta V_s$ : 电容越大,滤波效果(去耦效果)越好

# 作业1二阶RC高通滤波器



- 1、列写电路状态方程
- 2、列写以Vo为未知量的二阶微分方程
- 3、列写频域传递函数
- 4、从微分方程(或频域传递函数)说明关键参量: ξ, ω<sub>0</sub>
- 5、假设两个电容初始电压均为0,激励源为阶跃信号源 $v_s(t)=V_0U(t)$ ,用五要素法获得输出电压表达式(考察 $R_1=R_2=R$ , $C_1=C_2=C$ 的特殊情况)

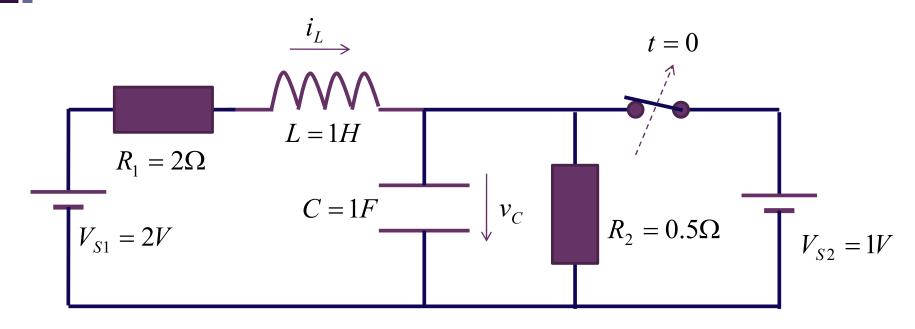
# 作业2分析与验证



- 开关在t=0时刻闭合。开关闭合前电路已经稳定。求开关闭合后, 电容电压v<sub>C</sub>(t)和电感电流i<sub>L</sub>(t)的变化规律
  - 课件已给电容电压V<sub>C</sub>(†)的变化规律,求i<sub>L</sub>(†)的变化规律
  - 验证

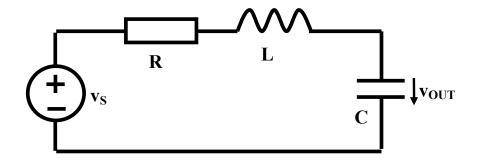
$$v_C(t) = v_L(t) = L \frac{di_L(t)}{dt} \qquad (t \ge 0)$$

### 作业3 非简单串并联电路 需要首先确定系统参量



- 1/用五要素法或待定系数法获得电容电压和电感电流
- 2/选作: 利用状态方程求解,求A矩阵特征根,用待定系数法求解

### CAD作业



### ■研究该电路

- 频域传递函数幅频特性和相频特性
- ■时域阶跃响应时域波形

#### ■参量

■ 阻尼系数=0.01,0.1,0.5,0.707,0.866,1,2,10,50,100

# 本节课内容在教材中的章节对应

■ P756-780: 二阶动态系统时域分析, 五要素法